











SN74LVC2244A

SCAS572L - APRIL 1996-REVISED JULY 2014

SN74LVC2244A Octal Buffer/Driver With 3-State Outputs

Features

- Operates From 1.65 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t_{pd} of 5.5 ns at 3.3 V
- Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$
- Typical V_{OHV} (Output V_{OH} Undershoot) >2 V at V_{CC} = 3.3 V, T_A = 25°C
- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V_{CC})
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

2 Applications

- Wearable Health and Fitness Devices
- **Network Switches**
- Servers
- **Tests and Measurements**

3 Description

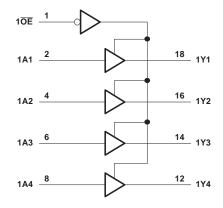
The SN74LVC2244A octal buffer/line driver is designed for 1.65-V to 3.6-V V_{CC} operation.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SSOP (20)	7.20 mm × 5.30 mm		
	SSOP (20)	8.65 mm × 3.90 mm		
SN74LVC2244A	TVSOP (20)	5.00 mm × 4.40 mm		
	SOIC (20)	12.80 mm × 7.50 mm		
	TSSOP (20)	6.50 mm × 4.40 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic



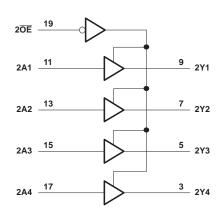




Table of Contents

1	Features 1	9 Detailed Description
2	Applications 1	9.1 Overview
3	Description 1	9.2 Functional Block Diagram
4	Simplified Schematic 1	9.3 Feature Description
5	Revision History2	9.4 Device Functional Modes
6	Pin Configuration and Functions	10 Application and Implementation 1
7	Specifications	10.1 Application Information 1
•	7.1 Absolute Maximum Ratings	10.2 Typical Application 1
	7.2 Handling Ratings	11 Power Supply Recommendations 1
	7.3 Recommended Operating Conditions	12 Layout 1
	7.4 Thermal Information	12.1 Layout Guidelines 1
	7.5 Electrical Characteristics 6	12.2 Layout Example 1
	7.6 Switching Characteristics, –40°C to 85°C	13 Device and Documentation Support 1
	7.7 Switching Characteristics, –40°C to 125°C	13.1 Trademarks 1
	7.8 Operating Characteristics	13.2 Electrostatic Discharge Caution 1
	7.9 Typical Characteristics	13.3 Glossary 1
8	Parameter Measurement Information 8	14 Mechanical, Packaging, and Orderable Information1

5 Revision History

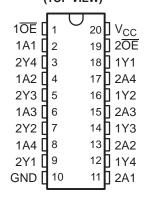
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Cł	nanges from Revision K (March 2005) to Revision L	Page
•	Updated document to new TI data sheet standards.	1
•	Deleted Ordering Information table.	1
•	Changed I _{off} bullet in Features list.	1
•	Added Applications.	
•	Added Pin Functions table	3
•	Added Handling Ratings table	4
•	Changed MAX ambient temperature to 125°C in Recommended Operating Conditions.	
•	Added Thermal Information table.	5
•	Added –40°C to 125°C temperature range in Electrical Characteristics table.	6
•	Added data to Switching Characteristics, -40°C to 85°C	6
•	Added Switching Characteristics table, -40°C to 125°C.	6
•	Changed Operating Characteristics table	7
•	Added Typical Characteristics.	7
•	Added Detailed Description section	
•	Added Application and Implementation section	10



6 Pin Configuration and Functions

DB, DBQ, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



Pin Functions

	PIN	1/0	DECODINE
NO.	NAME	I/O	DESCRIPTION
1	1 OE	1	Output Enable 1
2	1A1	1	1A1 Input
3	2Y4	0	2Y4 Output
4	1A2	1	1A2 Input
5	2Y3	0	2Y3 Output
6	1A3	1	1A3 Input
7	2Y2	0	2Y2 Output
8	1A4	1	1A4 Input
9	2Y1	Ο	2Y1 Output
10	GND	_	Ground Pin
11	2A1	1	2A1 Input
12	1Y4	0	1Y4 Output
13	2A2	1	2A2 Input
14	1Y3	Ο	1Y3 Output
15	2A3	1	2A3 Input
16	1Y2	0	1Y2 Output
17	2A4	I	2A4 Input
18	1Y1	0	1Y1 Output
19	2 OE	1	Output Enable 2
20	VCC	_	Power Pin



7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	6.5	V
V_{I}	Input voltage range (2)	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high	or low state (2) (3)	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	Continuous output current			mA
	Continuous current through V _{CC} or GND			±100	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT	
T _{stg}	Storage temperature rang	orage temperature range				
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	2000	\/	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	1000	V	

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

²⁾ The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the Recommended Operating Conditions table.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT	
\/	Cumply voltage	Operating	1.65	3.6	V	
V_{CC}	Supply voltage	Data retention only	1.5		V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V	
		V _{CC} = 2.7 V to 3.6 V	2			
		V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}		
V_{IL}	Low-level input voltage	V _{CC} = 2.3 V to 2.7 V		0.7	V	
		V _{CC} = 2.7 V to 3.6 V		0.8		
V _I	Input voltage		0	5.5	V	
1/	Outrot valta aa	High or low state	0	V _{CC}	V	
Vo	Output voltage	3-state	0	5.5	V	
		V _{CC} = 1.65 V		-2		
	High lavel autout average	V _{CC} = 2.3 V		-4	A	
I _{OH}	High-level output current	V _{CC} = 2.7 V		-8	mA	
		V _{CC} = 3 V		-12		
		V _{CC} = 1.65 V		2		
	Lave lavel autout average	V _{CC} = 2.3 V		4	A	
l _{OL}	Low-level output current	V _{CC} = 2.7 V		8	mA	
		V _{CC} = 3 V		12		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T _A	Operating free-air temperature		-40	125	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

7.4 Thermal Information

		SN74LVC2244A							
	THERMAL METRIC ⁽¹⁾	DB	DBQ	DGV	DW	NS	PW	UNIT	
		20 PINS							
$R_{\theta JA}$	Junction-to-ambient thermal resistance	94.5	94.7	114.7	88.3	74.7	102.5		
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	56.2	47.9	29.8	51.1	40.5	35.9		
$R_{\theta JB}$	Junction-to-board thermal resistance	49.7	45.0	56.2	50.9	42.3	53.5		
Ψ_{JT}	Junction-to-top characterization parameter	18.1	11.0	0.8	20.0	14.3	2.2	°C/W	
ΨЈВ	Junction-to-board characterization parameter	49.5	44.6	55.5	50.5	41.9	52.9		
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a		

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).



7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED			V	–40°C	to 85°C		–40°C	to 125°0		UNIT	
PARAMETER	TEST CONDITIONS		V _{CC}	MIN	TYP ⁽¹⁾	MAX	MIN	TYP ⁽¹⁾	MAX		
	I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} - 0.2			V _{CC} - 0.2				
	$I_{OH} = -2 \text{ mA}$		1.65 V	1.2			1.2				
	$I_{OH} = -4 \text{ mA}$		2.3 V	1.7			1.7			.,	
V_{OH}	10H = -4 IIIA		2.7 V	2.2			2.2			V	
	$I_{OH} = -6 \text{ mA}$		3 V	2.4			2.4				
	$I_{OH} = -8 \text{ mA}$		2.7 V	2			2				
	$I_{OH} = -12 \text{ mA}$		3 V	2			2				
	I _{OL} = 100 μA		1.65 V to 3.6 V			0.2			0.2).2	
	$I_{OL} = 2 \text{ mA}$		1.65 V			0.45			0.45		
	I _{OL} = 4 mA		2.3 V			0.7			0.7	٧	
V_{OL}			2.7 V			0.4			0.4		
	I _{OL} = 6 mA		3 V			0.55			0.55		
	I _{OL} = 8 mA		2.7 V			0.6			0.6		
V _{OL}	I _{OL} = 12 mA		3 V			8.0			8.0		
I _I	$V_{I} = 0 \text{ to } 5.5 \text{ V}$		3.6 V			±5			±5	μΑ	
I _{off}	V_I or $V_O = 5.5 \text{ V}$		0			±10			±10	μΑ	
I _{OZ}	V _O = 0 to 5.5 V		3.6 V			±10			±10	μA	
	$V_I = V_{CC}$ or GND		2.0.1/			10			10		
Icc	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}^{(2)}$	$I_{O} = 0$	3.6 V			10			10	μA	
ΔI _{CC}	One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at V_{CC} or GND	er	2.7 V to 3.6 V			500			500	μΑ	
C _i	$V_I = V_{CC}$ or GND		3.3 V		4			4		pF	
Co	$V_O = V_{CC}$ or GND		3.3 V		5.5			5.5		pF	

All typical values are at V_{CC} = 3.3 V, T_A = 25°C. This applies in the disabled state only.

7.6 Switching Characteristics, -40°C to 85°C

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1		V _{CC} = 2 ± 0.2	2.5 V 2 V	V _{CC} = 2	2.7 V	V _{CC} = 3 ± 0.3	3.3 V V	UNIT
	(INPOT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Υ		10.9		7.9		6.4	1.5	5.5	ns
t _{en}	ŌĒ	Υ		12.6		9.6		8.1	1	7.1	ns
t _{dis}	ŌĒ	Υ		12.1		7.8		7.3	1.5	6.8	ns

7.7 Switching Characteristics, -40°C to 125°C

over operating free-air temperature range (unless otherwise noted)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	Α	Υ		12.4		10		7.1	1.5	6.5	ns
t _{en}	ŌĒ	Υ		14.1		11.7		8.5	1	7.8	ns
t _{dis}	ŌĒ	Υ		13.6		9.9		7.8	1.5	7.6	ns

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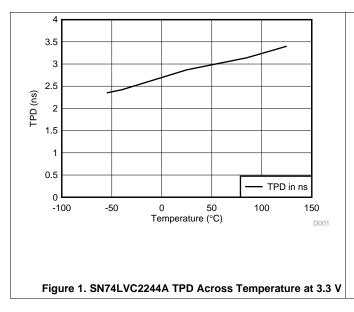


7.8 Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETER			TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT	
			CONDITIONS	TYP	TYP	TYP	0.411	
Power dissipation capacitance		Outputs enabled	f = 10 MHz	43	43	46	pF	
C_{pd}	per buffer/driver	Outputs disabled	I = IO MINZ	1	1	2	pr	

7.9 Typical Characteristics



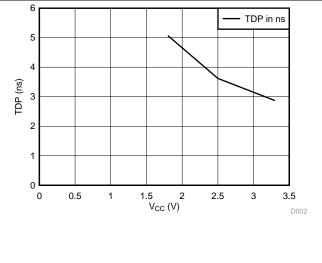
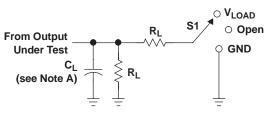


Figure 2. SN74LVC2244A TDP Across V_{CC} at 25°C



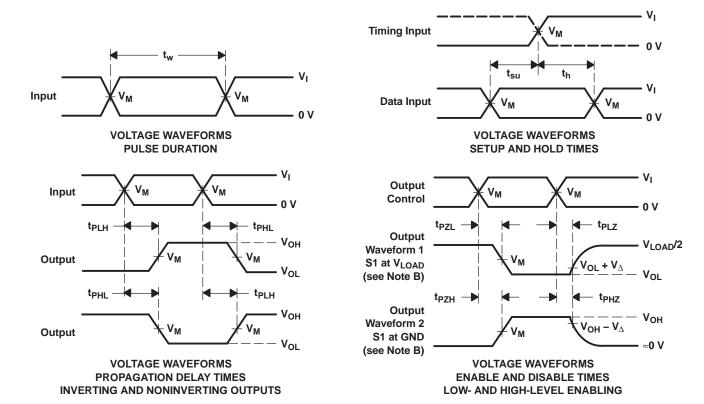
8 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

I OAD CIRCUIT			

.,	INPUTS		.,	.,		В	V	
V _{CC}	V_{I}	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_Δ	
1.8 V \pm 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V	
2.5 V \pm 0.2 V	V_{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	500 Ω	0.15 V	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms

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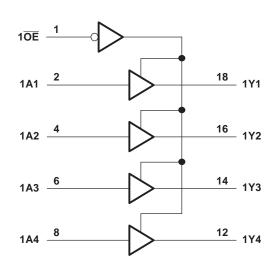


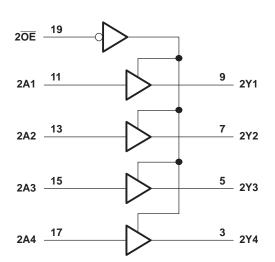
9 Detailed Description

9.1 Overview

This octal buffer and line driver is designed for 1.65-V to 3.6-V $_{\text{CC}}$ operation. The SN74LVC2244A device is organized as two 4-bit line drivers with separate output-enable ($_{\text{OE}}$) inputs. When $_{\text{OE}}$ is low, the device passes data from the A inputs to the Y outputs. When $_{\text{OE}}$ is high, the outputs are in the high-impedance state. The outputs, which are designed to sink up to 12 mA, include equivalent 26-ohm resistors to reduce overshoot and undershoot.

9.2 Functional Block Diagram





9.3 Feature Description

- Wide operating voltage range
 - Operates from 1.65 V to 3.6 V
- Allows down voltage translation
 - Inputs accept voltages to 5.5 V
- I_{off} Feature
 - Allows voltages on the inputs and outputs when V_{CC} is 0 V

9.4 Device Functional Modes

Table 1. Function Table (Each Buffer)

INP	JTS	OUTPUT
ŌĒ	Α	Υ
L	Н	Н
L	L	L
Н	X	Z



10 Application and Implementation

10.1 Application Information

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

10.2 Typical Application

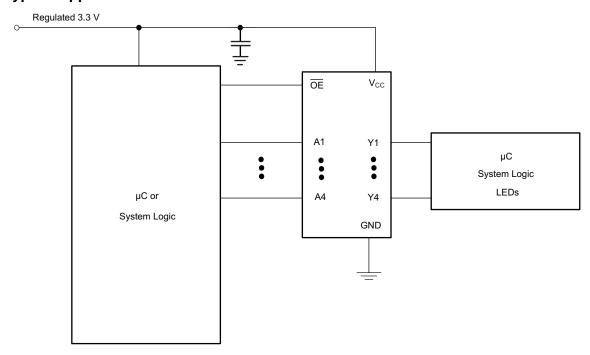


Figure 4. Typical Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

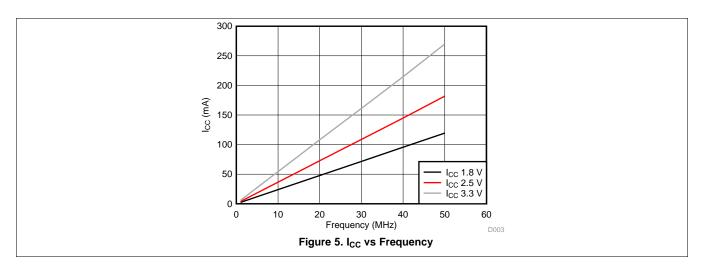
10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
 - Rise time and fall time specs: See ($\Delta t/\Delta V$) in the *Recommended Operating Conditions* table.
 - Specified high and low levels: See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}.
- 2. Recommend Output Conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part.
 - Outputs should not be pulled above V_{CC}.



Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ f is recommended; if there are multiple V_{CC} pins, then 0.01 μ f or 0.022 μ f is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ f and a 1 μ f are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 6 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the IOs, so they cannot float when disabled.

12.2 Layout Example

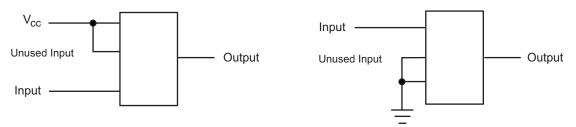


Figure 6. Layout Diagram



13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC2244ADBQR	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LVC2244A	Samples
SN74LVC2244ADBQRE4	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LVC2244A	Samples
SN74LVC2244ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244ADBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244ADGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244ADW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC2244A	Samples
SN74LVC2244ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC2244A	Samples
SN74LVC2244ADWRE4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC2244A	Samples
SN74LVC2244ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVC2244A	Samples
SN74LVC2244APW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244APWG4	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244APWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244APWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples
SN74LVC2244APWT	ACTIVE	TSSOP	PW	20	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LE244A	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.





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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL. Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

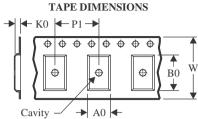
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TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC2244ADBQR	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74LVC2244ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVC2244ADGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC2244ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVC2244ANSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVC2244APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LVC2244APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



www.ti.com 3-Jun-2022



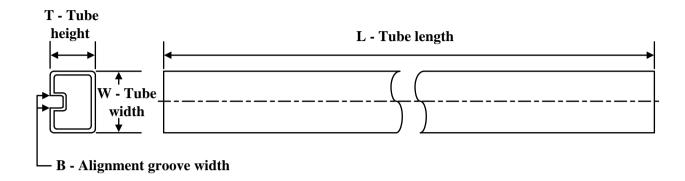
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC2244ADBQR	SSOP	DBQ	20	2500	356.0	356.0	35.0
SN74LVC2244ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LVC2244ADGVR	TVSOP	DGV	20	2000	356.0	356.0	35.0
SN74LVC2244ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVC2244ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVC2244APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LVC2244APWT	TSSOP	PW	20	250	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

TUBE

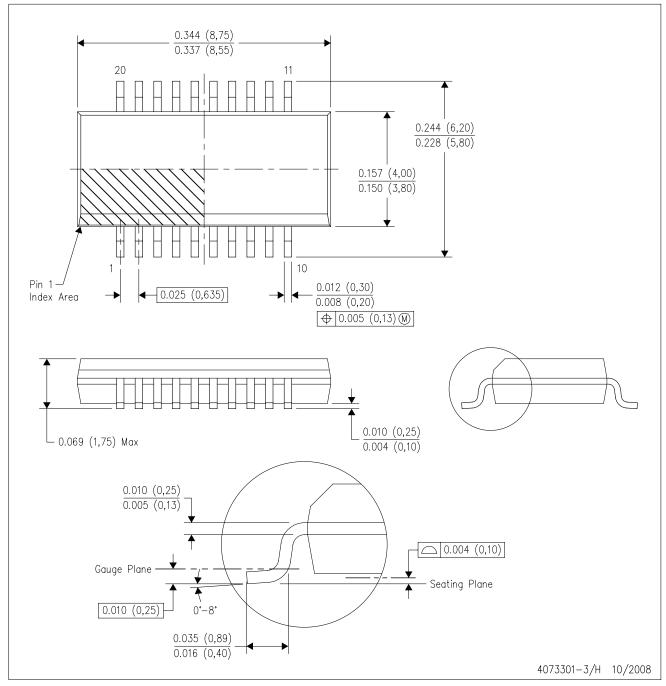


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74LVC2244ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LVC2244APW	PW	TSSOP	20	70	530	10.2	3600	3.5
SN74LVC2244APWG4	PW	TSSOP	20	70	530	10.2	3600	3.5

DBQ (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE

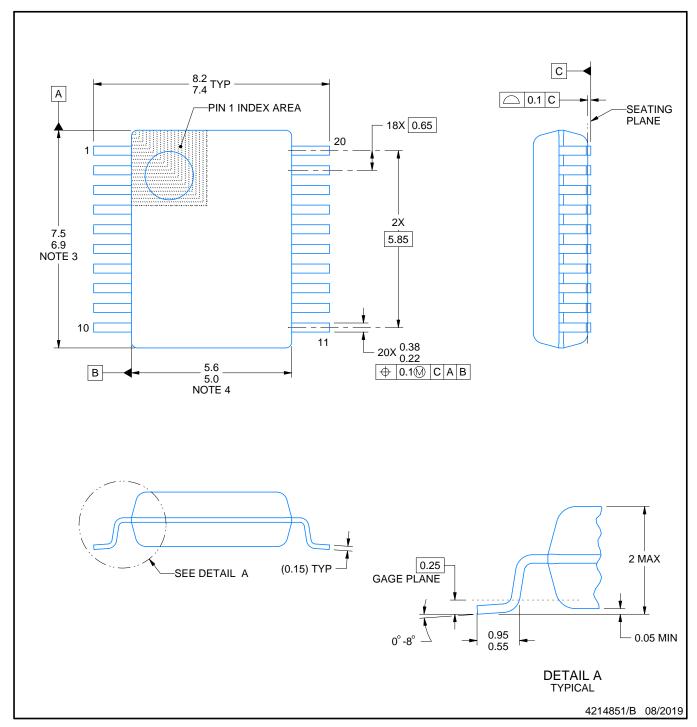


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



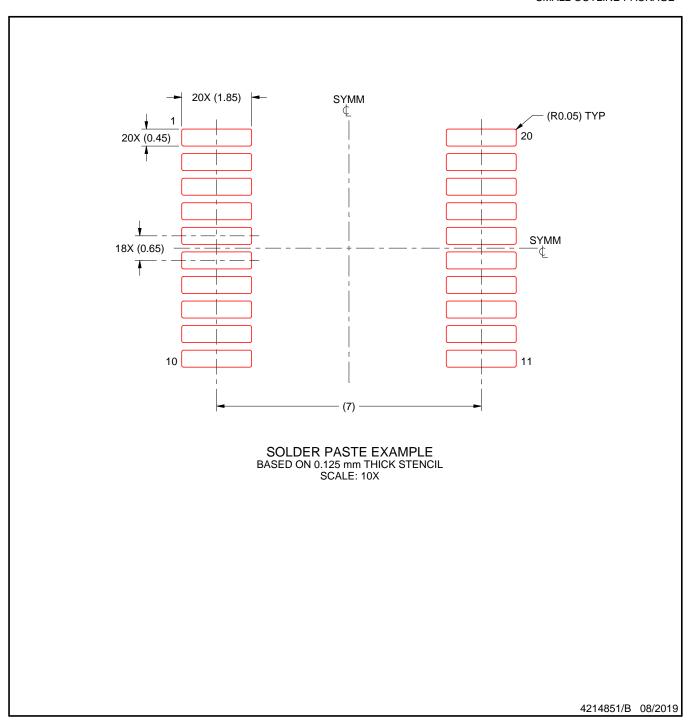


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

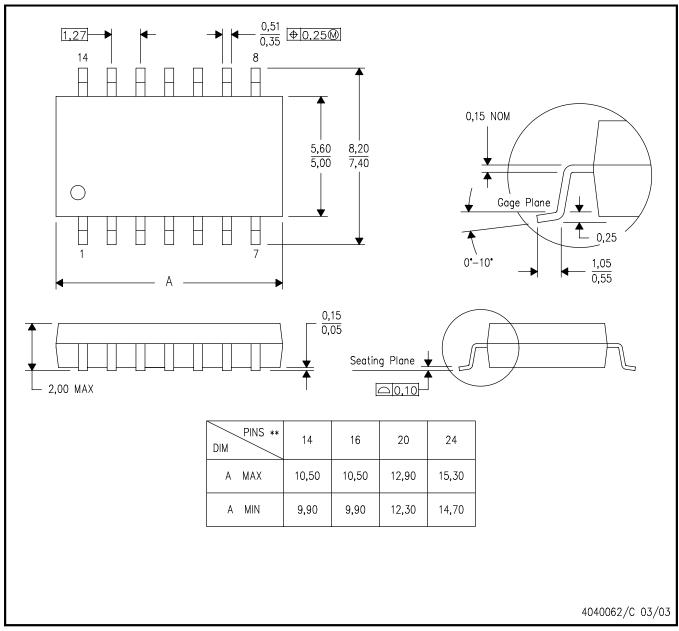


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



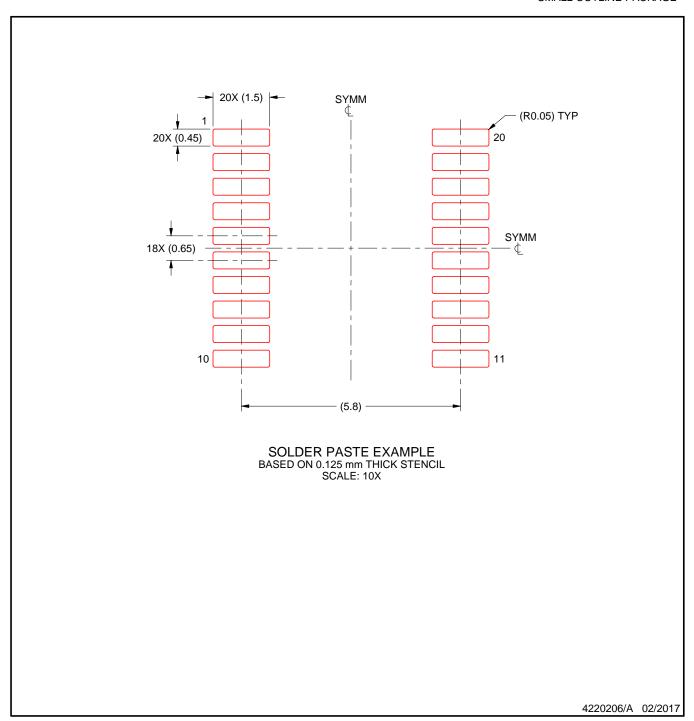


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





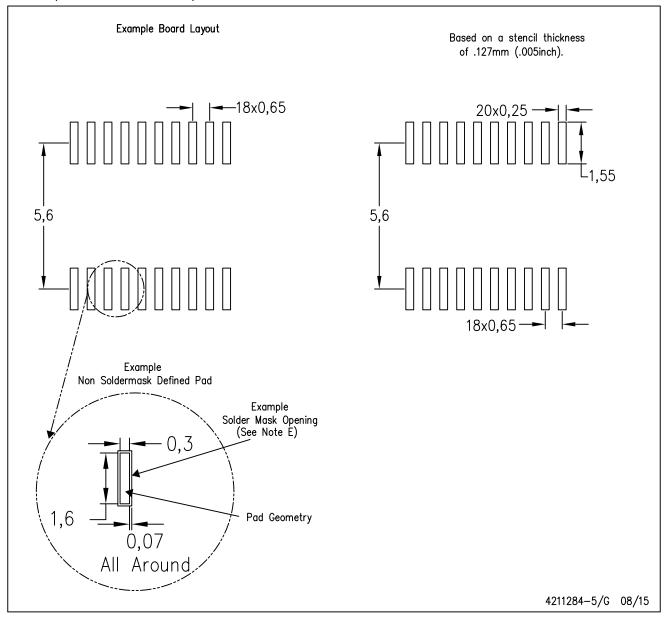
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



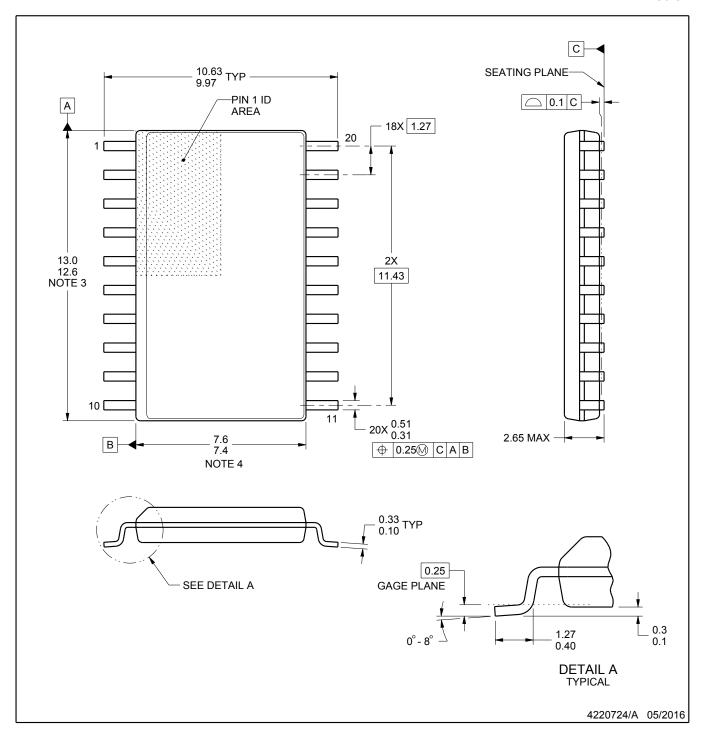
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SOIC



NOTES:

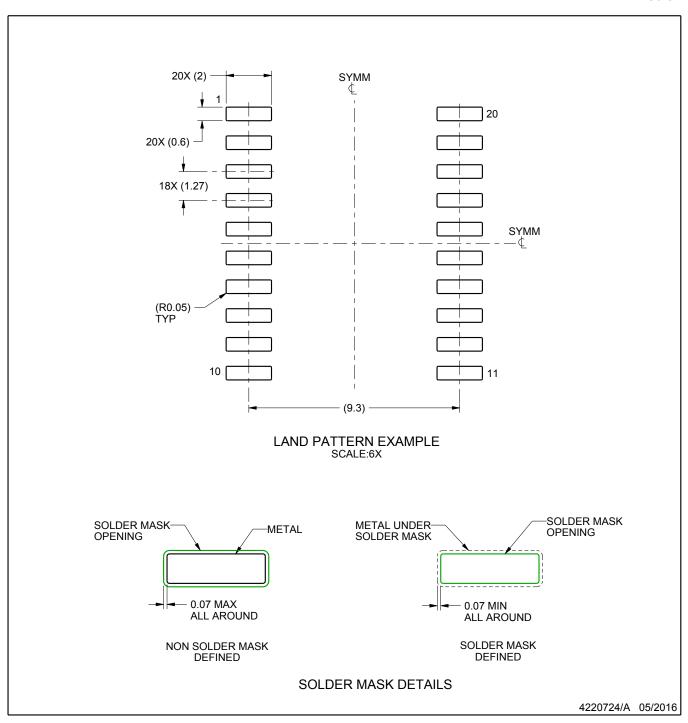
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC

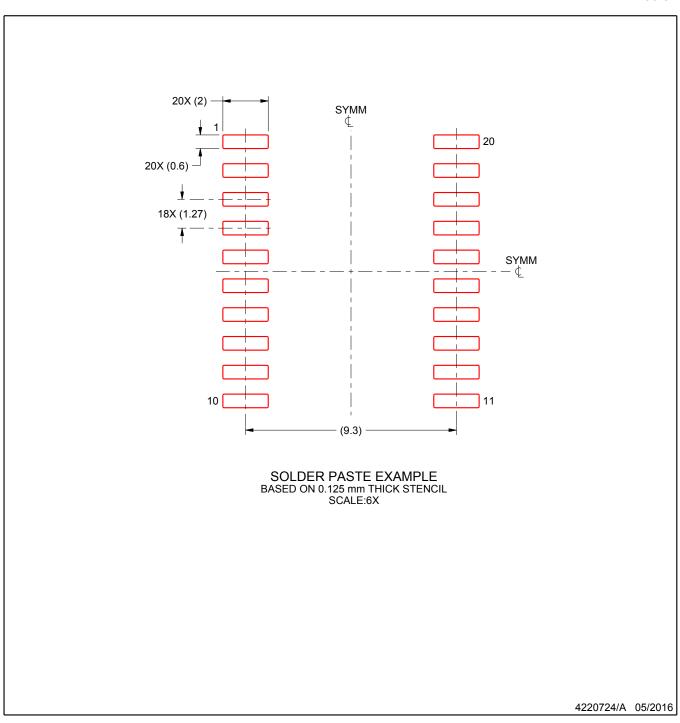


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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